## PRELIMINARY DATA SHEET



## **PHOTOCOUPLER**

# PS9822-1,-2

# 1 Mbps OPEN COLLECTOR OUTPUT TYPE 8-PIN SSOP (SO-8) HIGH-SPEED PHOTOCOUPLER

-NEPOC Series-

#### **DESCRIPTION**

The PS9822-1 and PS9822-2 are active-low type high-speed photocouplers that use a GaAlAs light-emitting diode on the input side and a photodetector IC that includes a photodiode and a signal processor on the same chip on the output side.

The PS9822-1, -2 are high-speed digital output type photocouplers designed specifically for low circuit current. The PS9822-2 is suitable for high density applications.

## **FEATURES**

· Supply Voltage

N rank: Vcc = 3.3 VL rank: Vcc = 5 V

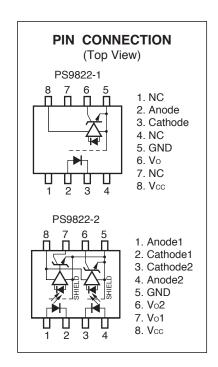
- Pulse width distortion (|tphl-tplh| = 200 ns MAX.)
- 40% reduction of mounting area (5-pin SOP × 2)
- · High-speed (1 Mbps)
- High isolation voltage (BV = 2 500 Vr.m.s.)
- Open collector output
- Ordering number of tape product: PS9822-1-F3: 1 500 pcs/reel

: PS9822-2-F3: 1 500 pcs/reel

· Pb-Free product

## **APPLICATIONS**

- · PoE (Power over Ethernet)
- · Measurement equipment
- · FA Network

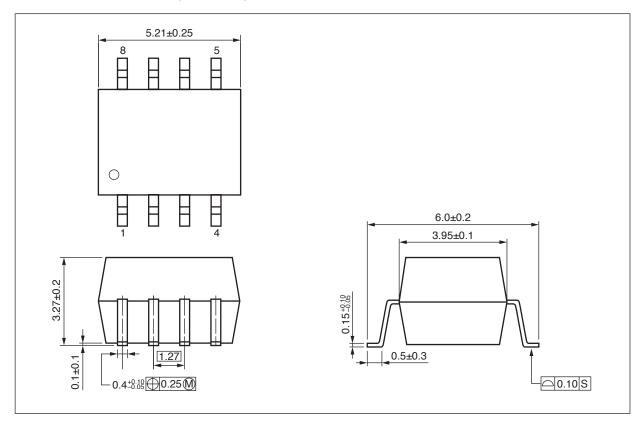


#### TRUTH TABLE

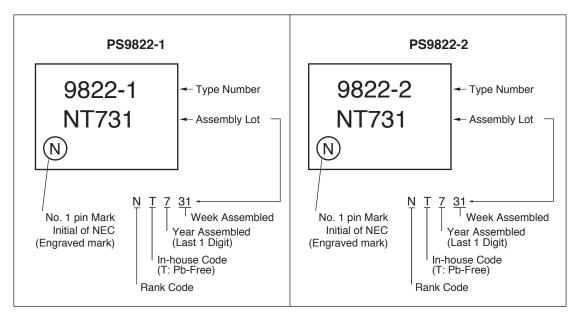
| LED | Output |
|-----|--------|
| ON  | L      |
| OFF | Н      |

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## PACKAGE DIMENSIONS (UNIT: mm)



## MARKING EXAMPLE



## **ORDERING INFORMATION**

| Part Number | Order Number   | Rank            | Solder Plating<br>Specification | Packing Style                |  |  |
|-------------|----------------|-----------------|---------------------------------|------------------------------|--|--|
| PS9822-1    | PS9822-1-AX    | N*1             | Pb-Free                         | 20 pcs (Tape 20 pcs cut)     |  |  |
|             |                | L*2             |                                 |                              |  |  |
| PS9822-1-F3 | PS9822-1-F3-AX | N <sup>*1</sup> |                                 | Embossed Tape 1 500 pcs/reel |  |  |
|             |                | L*2             |                                 |                              |  |  |
| PS9822-2    | PS9822-2-AX    | N*1             |                                 | 20 pcs (Tape 20 pcs cut)     |  |  |
|             |                | L*2             |                                 |                              |  |  |
| PS9822-2-F3 | PS9822-2-F3-AX | N*1             |                                 | Embossed Tape 1 500 pcs/reel |  |  |
|             |                | L*2             |                                 |                              |  |  |

\*1 N rank: Vcc = 3.3 V \*2 L rank: Vcc = 5 V

## ABSOLUTE MAXIMUM RATINGS (TA = 25°C, unless otherwise specified)

| Parameter                       |                     | Symbol           | Ratings     |                  | Unit    |  |   |
|---------------------------------|---------------------|------------------|-------------|------------------|---------|--|---|
|                                 |                     |                  | PS9822-1    | PS9822-2         |         |  |   |
| Diode                           | Forward Current     | lF               | 20 ⁴        | 15 <sup>*2</sup> | mA      |  |   |
|                                 | Reverse Voltage     | VR               | Ę           | 5                |         |  |   |
| Detector                        | Supply Voltage      | Vcc              | 7           |                  | 7       |  | V |
|                                 | Output Voltage      | Vo               | 7           |                  | V/ch    |  |   |
|                                 | Output Current      | lo               | 25          |                  | mA/ch   |  |   |
|                                 | Power Dissipation*3 | Pc               | 40          |                  | mW/ch   |  |   |
| Isolation Voltage <sup>*⁴</sup> |                     | BV               | 2 500       |                  | Vr.m.s. |  |   |
| Operating Ambient Temperature   |                     | Та               | -40 to +100 |                  | °C      |  |   |
| Storage Temperature             |                     | T <sub>stg</sub> | -55 to +125 |                  | °C      |  |   |

- \*1 Reduced to 0.3 mA/°C at  $T_A = 60$ °C or more.
- \*2 Reduced to 0.1 mA/°C at  $T_A = 60$ °C or more.
- \*3 Applies to output pin Vo (collector pin). Reduced to 1.5 mW/°C at TA = 65°C or more.
- \*4 AC voltage for 1 minute at T<sub>A</sub> = 25°C, RH = 60% between input and output. Pins 1-4 shorted together, 5-8 shorted together.

## RECOMMENDED OPERATING CONDITIONS

| Parameter                            |        | Symbol          | MIN. | TYP. | MAX. | Unit |
|--------------------------------------|--------|-----------------|------|------|------|------|
| Low Level Input Voltage              |        | V <sub>FL</sub> | 0    |      | 0.8  | V    |
| High Level Input Current             |        | lғн             | 6.3  | 10   | 12.5 | mA   |
| Supply Voltage                       | N rank | Vcc             | 2.7  | 3.3  | 3.6  | V    |
|                                      | L rank |                 | 4.5  | 5.0  | 5.5  |      |
| Pull-up Resistance                   |        | RL              | 330  |      | 4 k  | Ω    |
| TLL (R <sub>L</sub> = 1.0 kΩ, loads) |        | N               |      |      | 5    |      |

## ELECTRICAL CHARACTERISTICS: N rank (TA = -40 to +100°C, unless otherwise specified)

| Parameter |  | Symbol           | Conditions  | MIN. | TYP.*1 | MAX. | Unit  |
|-----------|--|------------------|---|------|--------|------|-------|
| Diode     | Forward Voltage                        | VF               | IF = 10 mA, TA = 25°C   |      | 1.6    | 1.8  | ٧     |
|           | Reverse Current                        | IR               | VR = 3 V, TA = 25°C   |      |        | 10   | μΑ    |
|           | Terminal Capacitance                   | Ct               | V = 0 V, f = 1 MHz, T <sub>A</sub> = 25°C   |      | 30     |      | pF    |
| Detector  | High Level Output Current              | Іон              | Vcc = Vo = 3.3 V, V <sub>F</sub> = 0.8 V  |      | 1      | 100  | μΑ    |
|           | Low Level Output Voltage <sup>*2</sup> | Vol              | Vcc = 3.3 V, IF = 5 mA, IoL = 13 mA   |      | 0.2    | 0.6  | ٧     |
|           | High Level Supply Current              | Іссн             | Vcc = 3.3 V, I <sub>F</sub> = 0 mA, Vo = Open   |      |        | 2    | mA/ch |
|           | Low Level Supply Current               | Iccl             | Vcc = 3.3 V, I <sub>F</sub> = 10 mA, Vo = Open  |      |        | 3    |       |
| Coupled   | Threshold Input Current (H → L)        | IFHL             | $Vcc = 3.3 \text{ V}, Vo = 0.8 \text{ V}, RL = 350 \Omega$  |      |        | 5    | mA    |
|           | Isolation Resistance                   | Ri-o             | V <sub>I-O</sub> = 1 kV <sub>DC</sub> , RH = 40 to 60%,<br>T <sub>A</sub> = 25°C  | 1011 |        |      | Ω     |
|           | Isolation Capacitance                  | C <sub>I-O</sub> | V = 0 V, f = 1 MHz, T <sub>A</sub> = 25°C   |      | 0.6    |      | pF    |
|           | Propagation Delay Time (H → L)         | <b>t</b> PHL     | $\label{eq:Vcc} V_{\text{CC}} = 3.3 \; \text{V}, \; \text{R}_{\text{L}} = 350 \; \Omega, \; \text{I}_{\text{F}} = 7.5 \; \text{mA}, \\ \text{V}_{\text{THAL}} = \text{V}_{\text{THLH}} = 1.5 \; \text{V}$ |      |        | 500  | ns    |
|           | Propagation Delay Time (L → H)         | <b>t</b> PLH     |   |      |        | 700  |       |
|           | Pulse Width Distortion (PWD)           | трнс-трсн        | $\begin{aligned} &\text{Vcc} = 3.3 \text{ V, RL} = 350 \ \Omega, \text{ I}_{\text{F}} = 7.5 \text{ mA}, \\ &\text{V}_{\text{THHL}} = \text{V}_{\text{THLH}} = 1.5 \text{ V} \end{aligned}$                |      |        | 200  | ns    |

<sup>\*1</sup> Typical values at  $T_A = 25^{\circ}C$ 

<sup>\*2</sup> Because Vol of 2 V or more may be output when LED current input and when output supply of Vcc = 2.6 V or less, it is important to confirm the characteristics (operation with the power supply on and off) during design, before using this device.

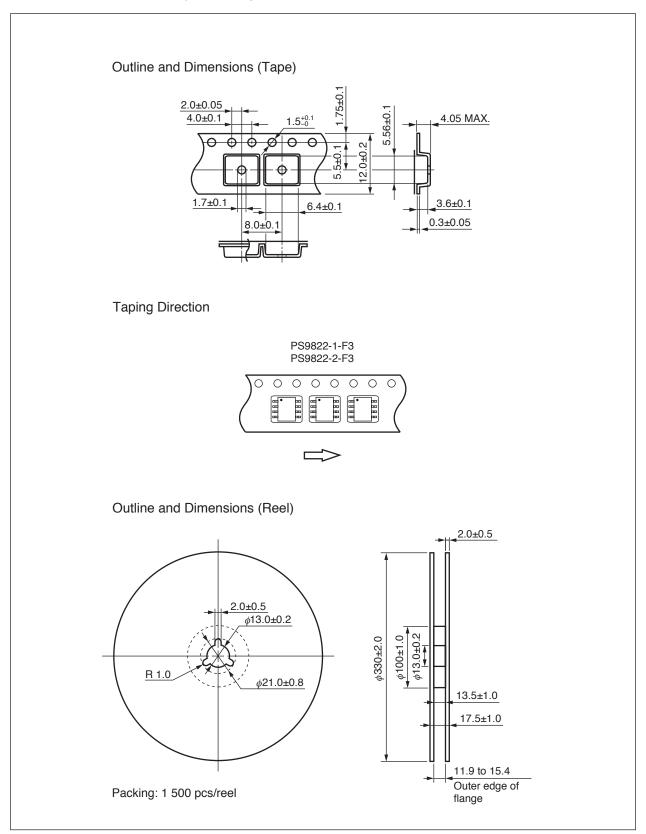
## ELECTRICAL CHARACTERISTICS: L rank ( $T_A = -40 \text{ to } +100^{\circ}\text{C}$ , unless otherwise specified)

| Parameter |  | Symbol           | Conditions   | MIN.             | TYP.*1 | MAX. | Unit  |
|-----------|--|------------------|--|------------------|--------|------|-------|
| Diode     | Forward Voltage                        | VF               | IF = 10 mA, T <sub>A</sub> = 25°C  |                  | 1.6    | 1.8  | ٧     |
|           | Reverse Current                        | IR               | VR = 3 V, TA = 25°C  |                  |        | 10   | μΑ    |
|           | Terminal Capacitance                   | Ct               | V = 0 V, f = 1 MHz, T <sub>A</sub> = 25°C  |                  | 30     |      | pF    |
| Detector  | High Level Output Current              | Іон              | Vcc = Vo = 5 V, V <sub>F</sub> = 0.8 V   |                  | 1      | 100  | μΑ    |
|           | Low Level Output Voltage <sup>*2</sup> | Vol              | Vcc = 5 V, IF = 5 mA, IoL = 13 mA  |                  | 0.2    | 0.6  | ٧     |
|           | High Level Supply Current              | Іссн             | Vcc = 5 V, I <sub>F</sub> = 0 mA, Vo = Open  |                  |        | 2.5  | mA/ch |
|           | Low Level Supply Current               | Iccl             | Vcc = 5 V, I <sub>F</sub> = 10 mA, Vo = Open   |                  |        | 3.5  |       |
| Coupled   | Threshold Input Current (H → L)        | IFHL             | $V_{\text{CC}} = 5 \text{ V}, \text{ V}_{\text{O}} = 0.8 \text{ V}, \text{ R}_{\text{L}} = 350 \Omega$   |                  |        | 5    | mA    |
|           | Isolation Resistance                   | Ri-o             | V <sub>I-O</sub> = 1 kV <sub>DC</sub> , RH = 40 to 60%,<br>T <sub>A</sub> = 25°C   | 10 <sup>11</sup> |        |      | Ω     |
|           | Isolation Capacitance                  | C <sub>I-O</sub> | V = 0 V, f = 1 MHz, T <sub>A</sub> = 25°C  |                  | 0.6    |      | pF    |
|           | Propagation Delay Time (H → L)         | <b>t</b> PHL     | $V_{\text{CC}} = 5 \text{ V, RL} = 350 \ \Omega, \text{ Ir} = 7.5 \text{ mA},$ $V_{\text{THHL}} = V_{\text{THLH}} = 1.5 \text{ V}$                                     |                  |        | 500  | ns    |
|           | Propagation Delay Time (L → H)         | <b>t</b> PLH     |  |                  |        | 700  |       |
|           | Pulse Width Distortion (PWD)           | tрнс-tрсн        | $\label{eq:Vcc} \begin{array}{l} \mbox{Vcc} = 5 \mbox{ V, RL} = 350 \ \Omega, \mbox{ IF} = 7.5 \mbox{ mA}, \\ \mbox{VTHHL} = \mbox{VTHLH} = 1.5 \mbox{ V} \end{array}$ |                  |        | 200  | ns    |

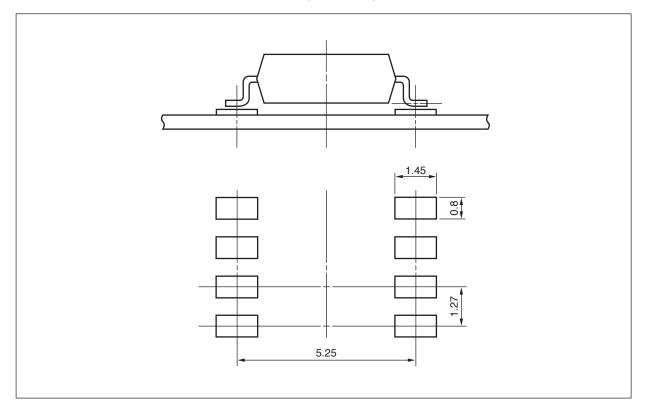
<sup>\*1</sup> Typical values at  $T_A = 25^{\circ}C$ 

<sup>\*2</sup> Because Vol of 2 V or more may be output when LED current input and when output supply of Vcc = 2.6 V or less, it is important to confirm the characteristics (operation with the power supply on and off) during design, before using this device.

## TAPING SPECIFICATIONS (UNIT: mm)



# RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



#### **NOTES ON HANDLING**

#### 1. Recommended soldering conditions

## (1) Infrared reflow soldering

· Peak reflow temperature 260°C or below (package surface temperature)

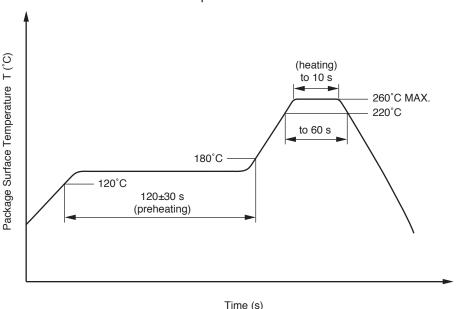
· Time of peak reflow temperature 10 seconds or less · Time of temperature higher than 220°C 60 seconds or less

• Time to preheat temperature from 120 to 180°C 120±30 s · Number of reflows Three

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

## Recommended Temperature Profile of Infrared Reflow



Time (s)

#### (2) Wave soldering

 Temperature 260°C or below (molten solder temperature)

 Time 10 seconds or less

· Preheating conditions 120°C or below (package surface temperature)

· Number of times One (Allowed to be dipped in solder including plastic mold portion.)

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

#### (3) Soldering by soldering iron

 Peak temperature (lead part temperature) 350°C or below · Time (each pins) 3 seconds or less

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead.

(b) Please be sure that the temperature of the package would not be heated over 100°C.

#### (4) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

## 2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

#### **USAGE CAUTIONS**

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. By-pass capacitor of 0.1  $\mu$ F is used between Vcc and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
- 3. Avoid storage at a high temperature and high humidity.

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#### Caution

**GaAs Products** 

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
  - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.